

Challenges & Experiences in Scaling up TOPCon n-Type Manufacturing

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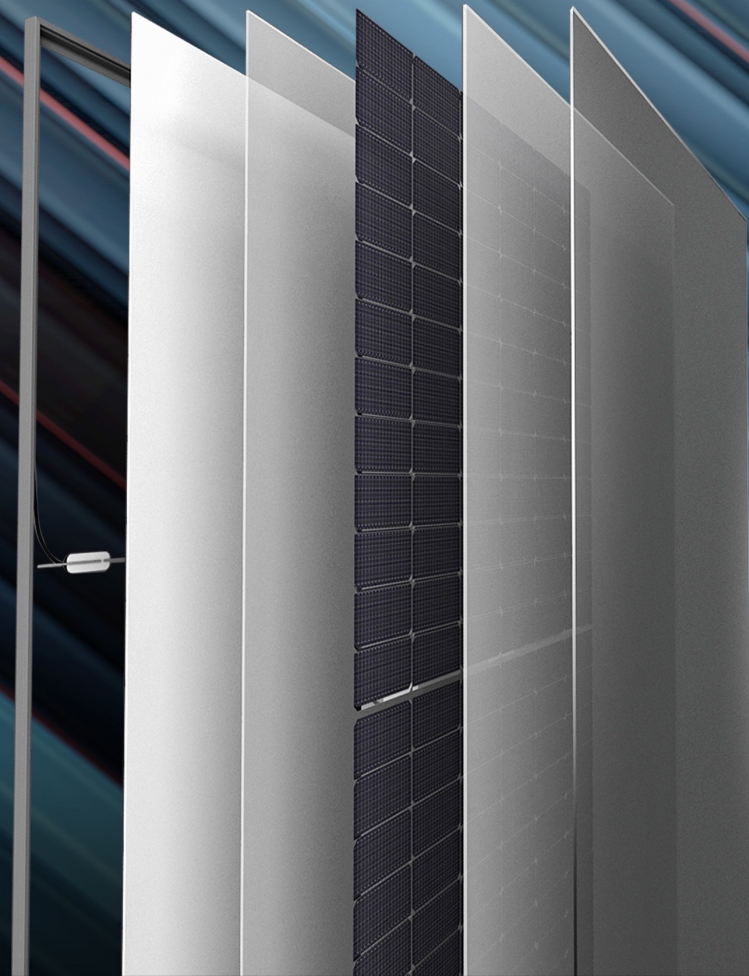
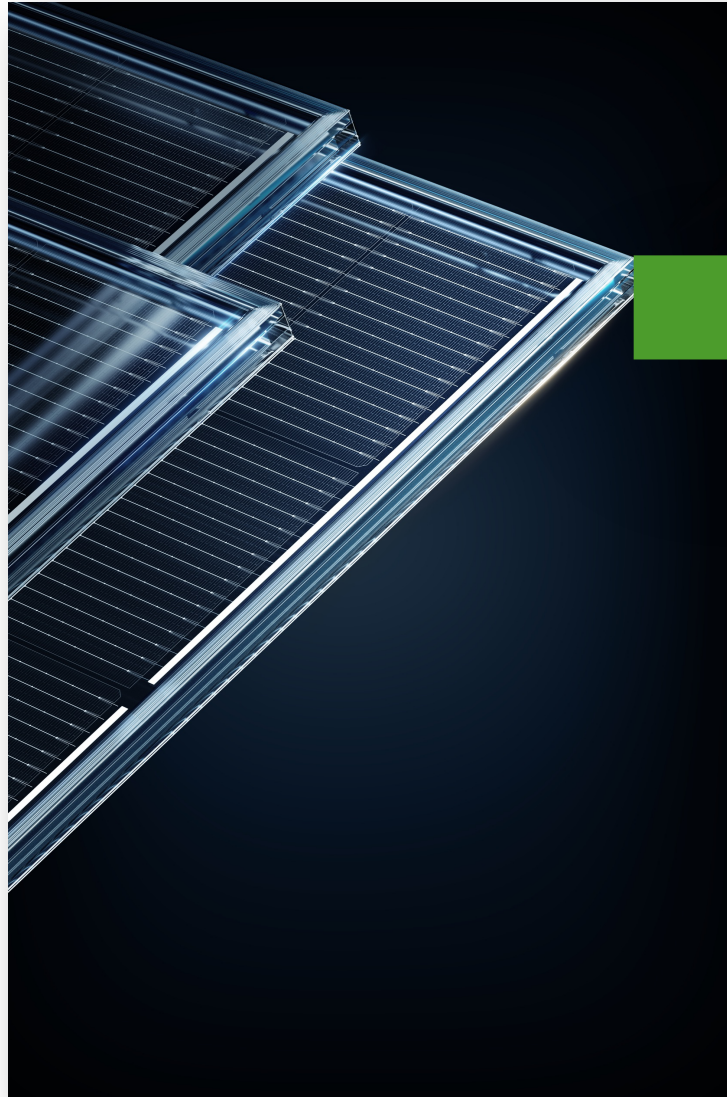


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05 Conclusions

Jinko Performance: Global Leader

150GW

Delivered

* 2023 Q1

No.1

2016-2019
Module Shipments

25

World Records

110GW

Total Module
Capacity

* 2023 Q4

55GW

N-type Module
Capacity

* 2023 Q4

15%

Market Share

**Data as of 2023 Q2

Global Leader in Technological Innovation



1702

Authorized Patents



2278

R&D Team



409

Patents applications



2.637B (CNY)

R&D Investments

The 25th Time World Record

Achieved by Jinko Solar

The highest conversion efficiency of

182 n-type TOPCon cell reaches **26.89%**

& in **n-type TOPCon tandem 32.33%**

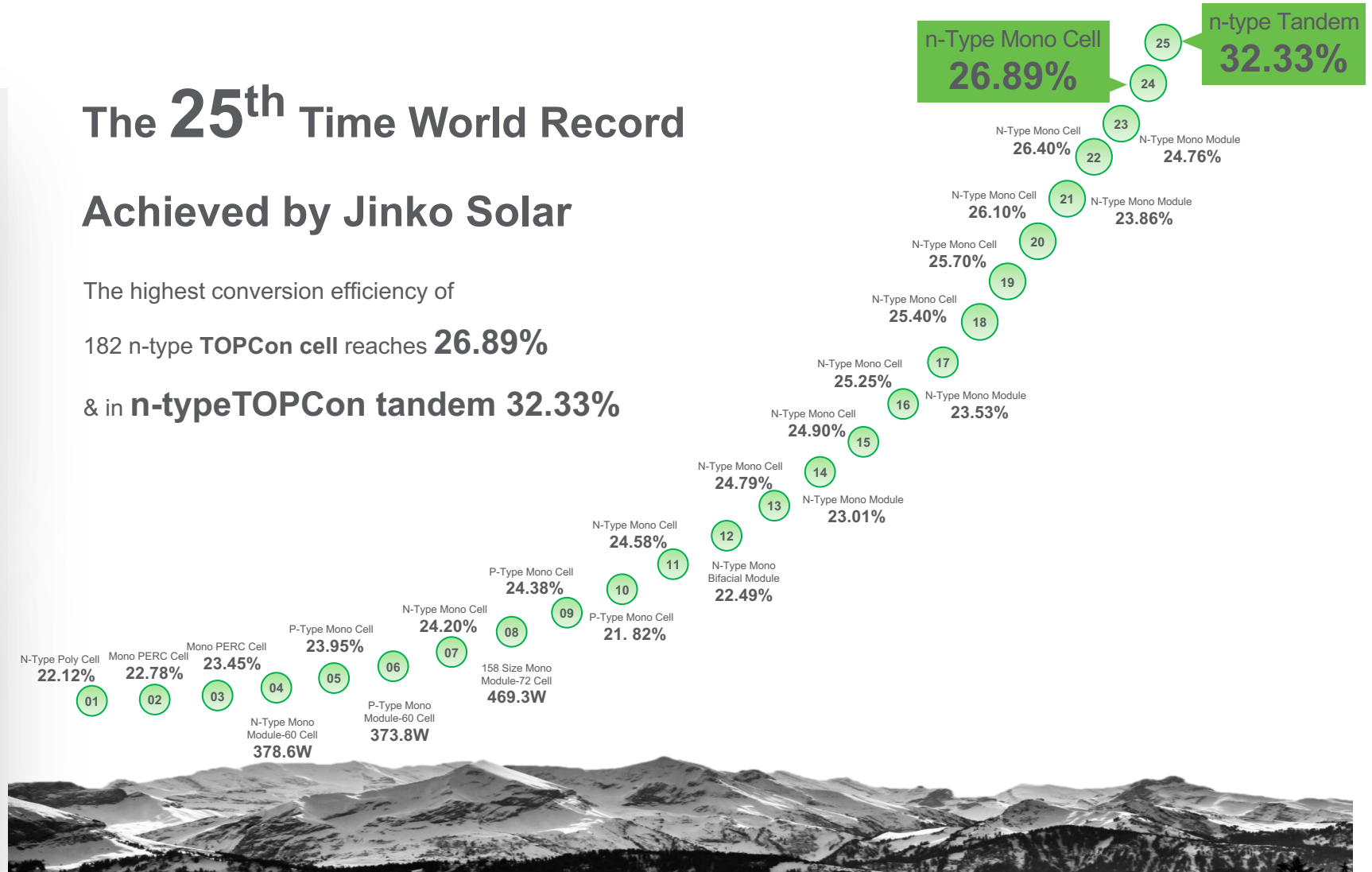
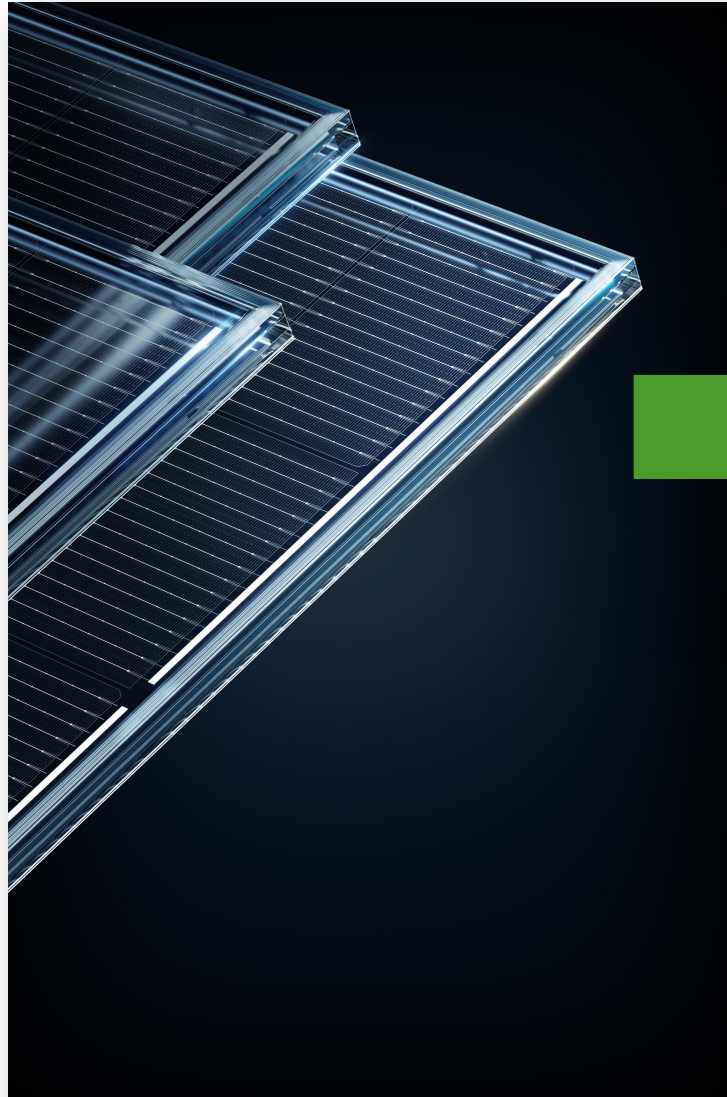


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Technical Roadmap: Why TOPCon?

Higher Theoretical Limits

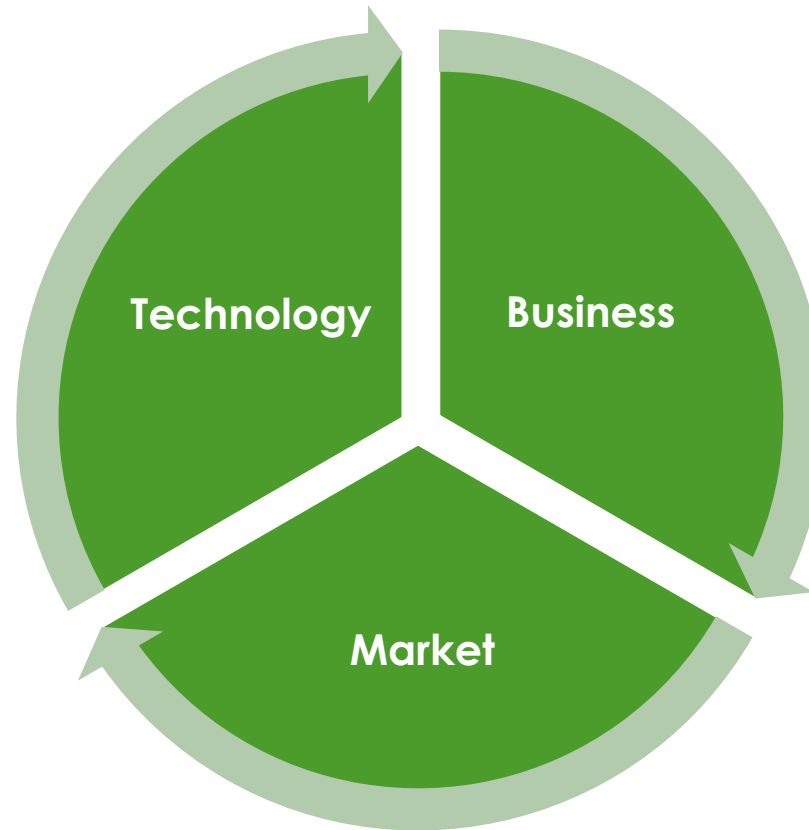
$\eta = 28.7\%$ vs. Others^[1,2]

Mass Production Viability

Lowered delamination, hotspot, and moisture risks

Maturity & Compatibility

PERC experience



Costs
Supply Chain
Operational Efficiency

Market Demand & Trends
Regulatory Landscape

[1] Brendel, R., Rienaeker, M. & Peibst, R. 2016, "A quantitative measure for the carrier selectivity of contacts to solar cells", Proc. 32nd EU PVSEC, Munich, Germany, doi:10.4229/EUPVSEC201620162CO.4.1.

[2] Brendel, R. & Peibst, R. 2016, "Contact selectivity and efficiency in crystalline silicon photovoltaics", IEEE J. Photovolt., Vol. 6, No. 6, pp.1413–1420, doi:10.1109/JPHOTOV.2016.2598267.

Technical Roadmap: Development trend

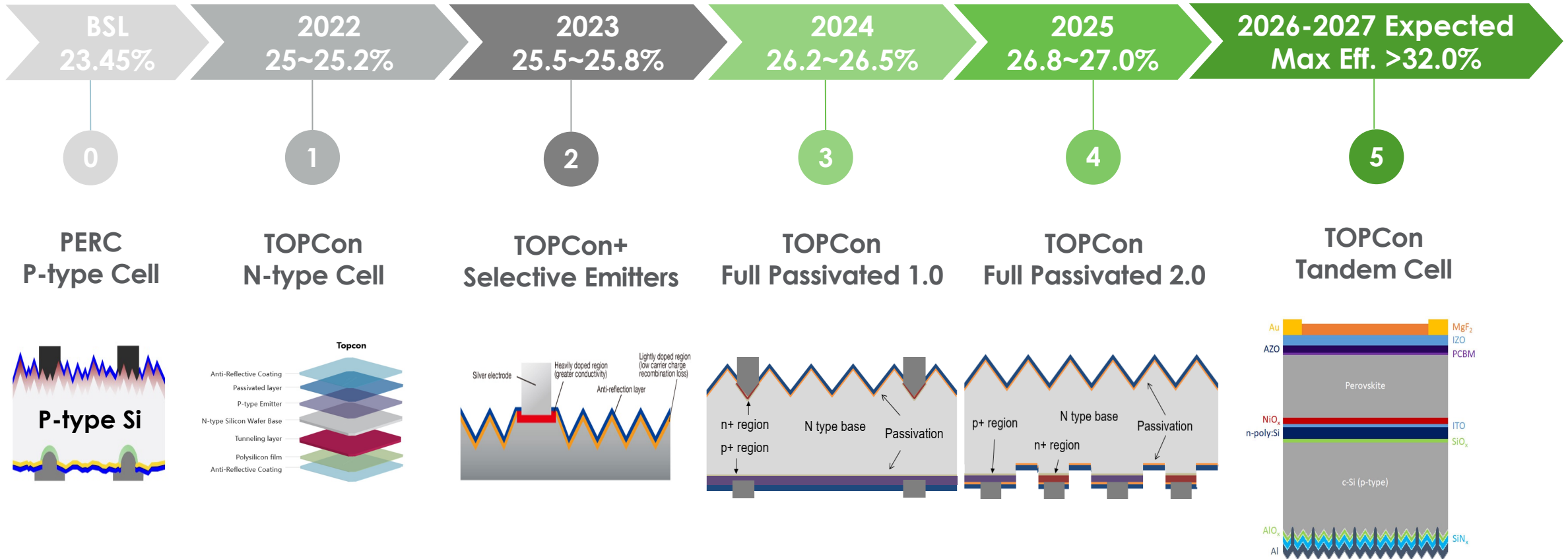
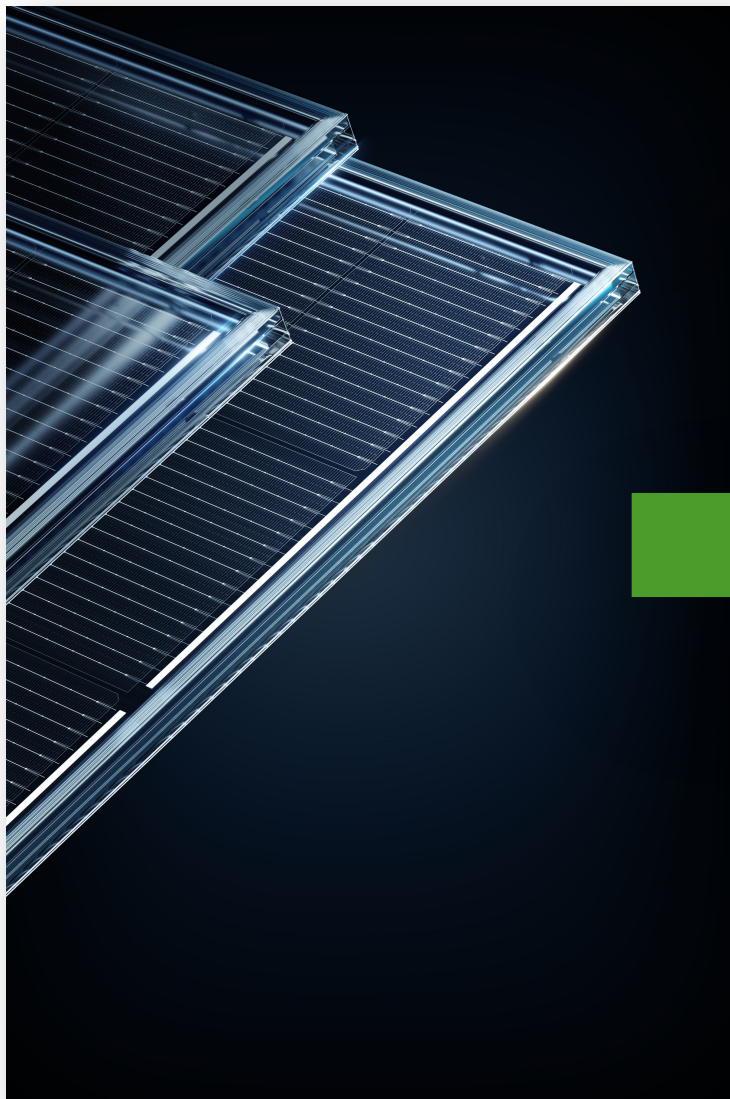
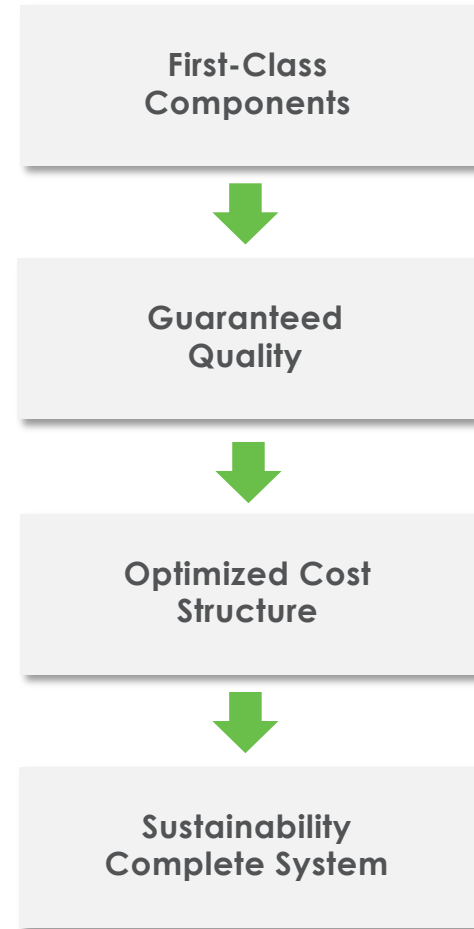
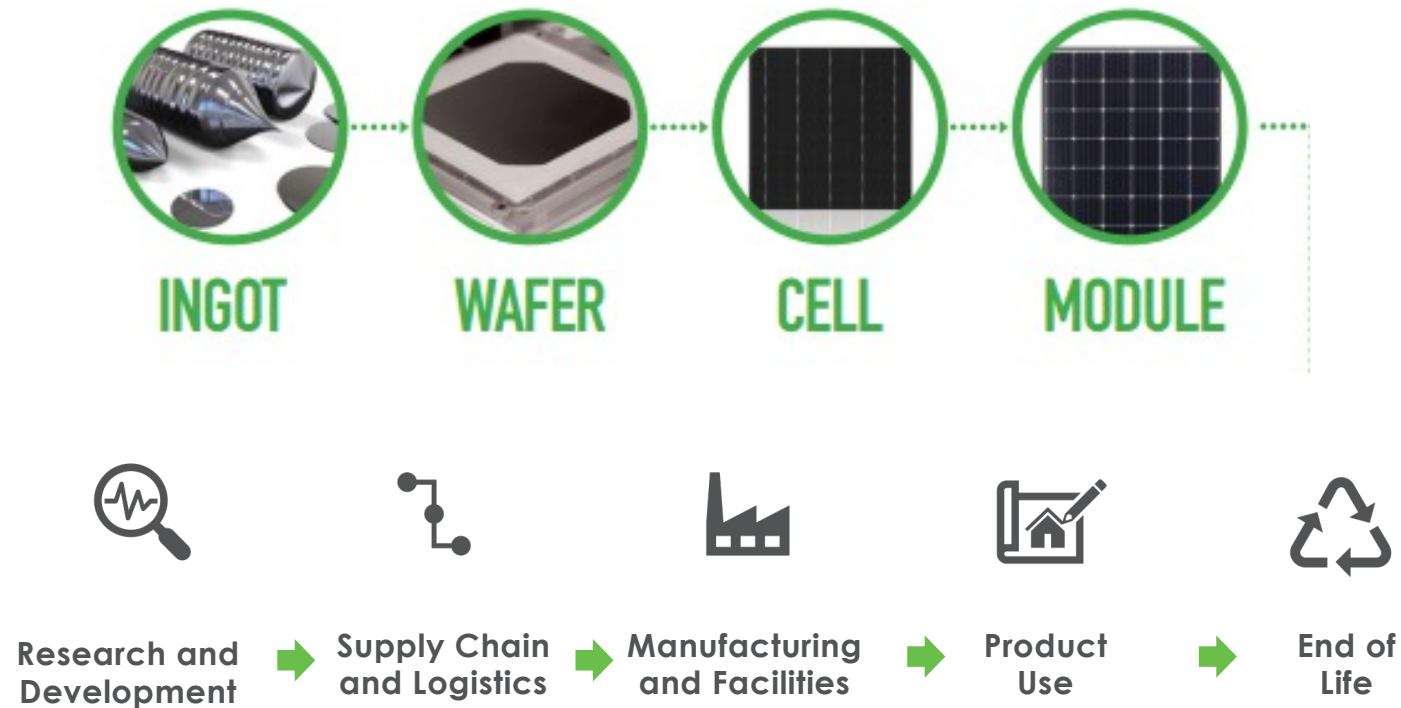


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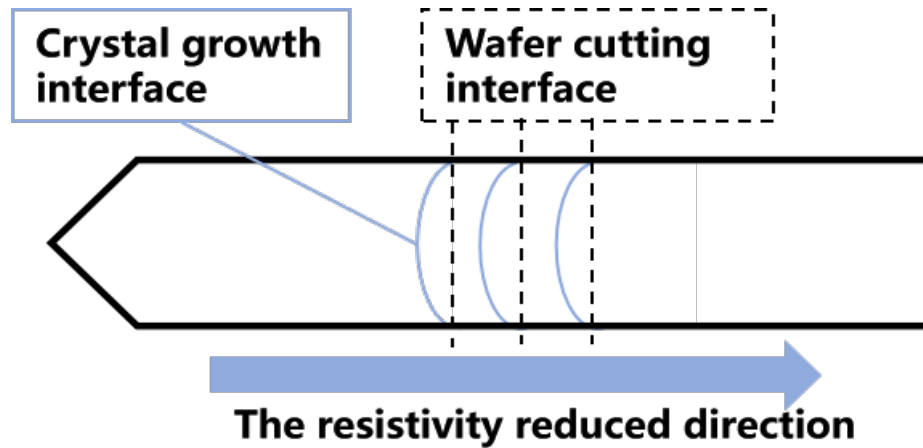


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- 05 Final conclusions

Vertically Integrated Production

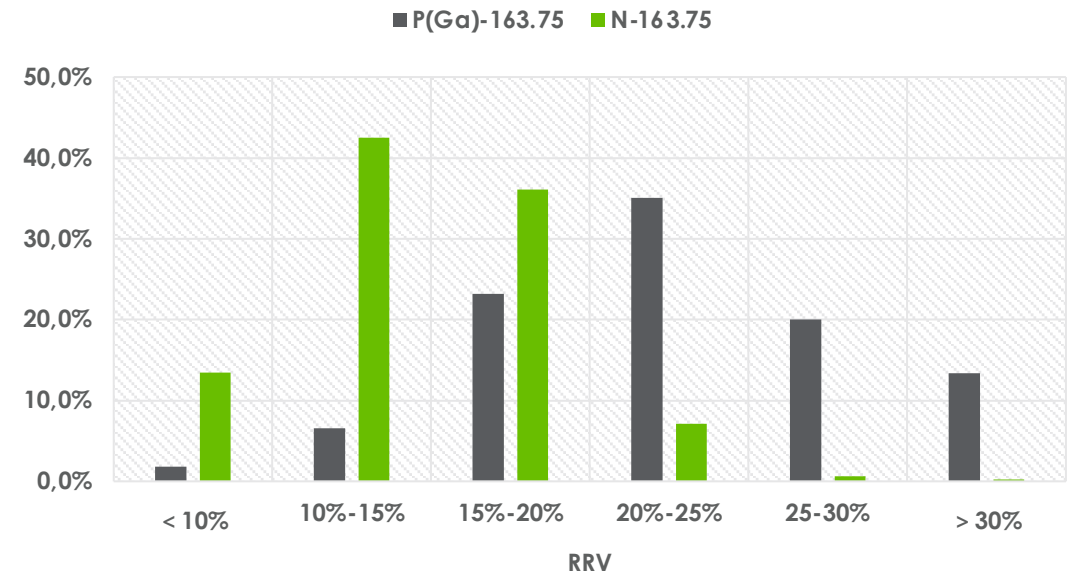


Industrial challenges: Ingot –wafer- and final quality



- **Uniform Growth:** The solidification at the ingot growth interface is consistent, maintaining **uniform resistivity**
- **Vertical Cutting Impact:** Vertical wafer cutting introduces varied resistivity across different points on the wafer.
- **Larger sizes, larger differences:** he resistivity variation intensifies with larger wafer sizes
- **n-type vs.p-type:** due to the segregation coefficient difference, **n-type wafers are more uniform.**

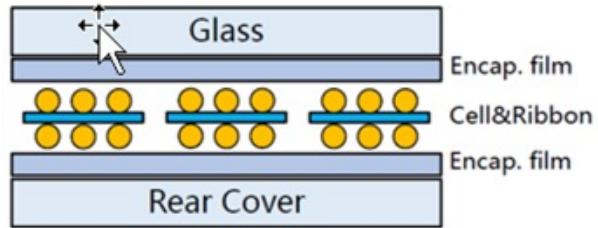
RRV distribution of different doped types



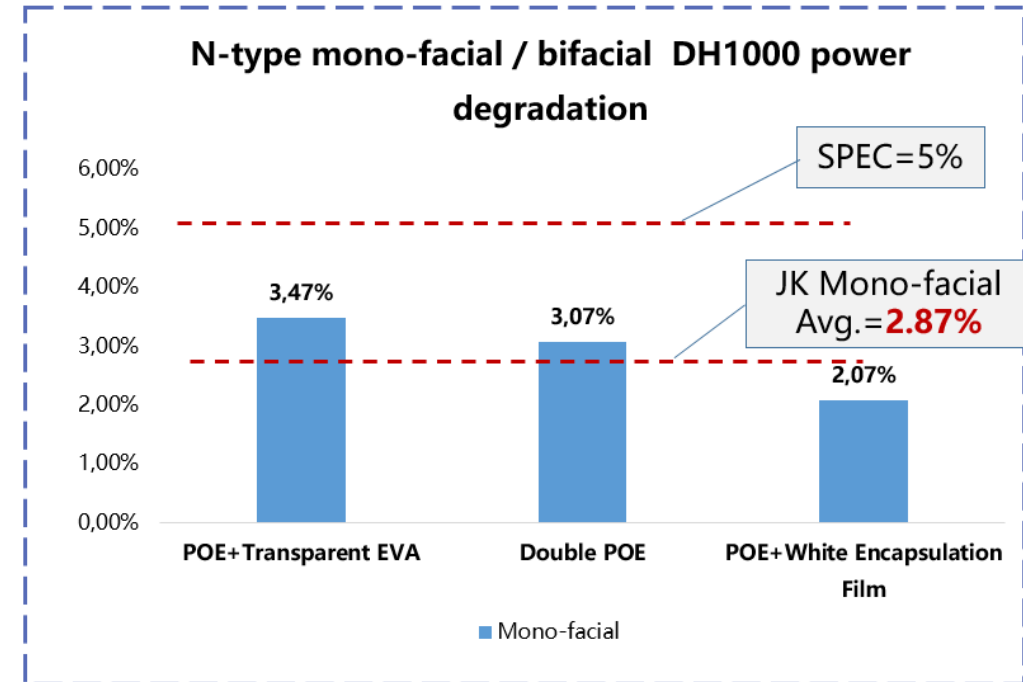
- The RRV (radial resistivity variation) value of the P type wafers with Ga doped is higher than the N type wafers with P doped.
- As the wafer size increases further, **RRV challenge for p-type is more severe than n-type.**

Industrial challenges: BOM selection- Encapsulant

n-Module Encap. Trend



	EVA	POE
Manufacturing difficulty	*	**
Curing Speed	***	**
Adhesion to Glass	***	**
Reliability	***	***
Anti PID	**	***
WVTR	*	**
Cost	**	***

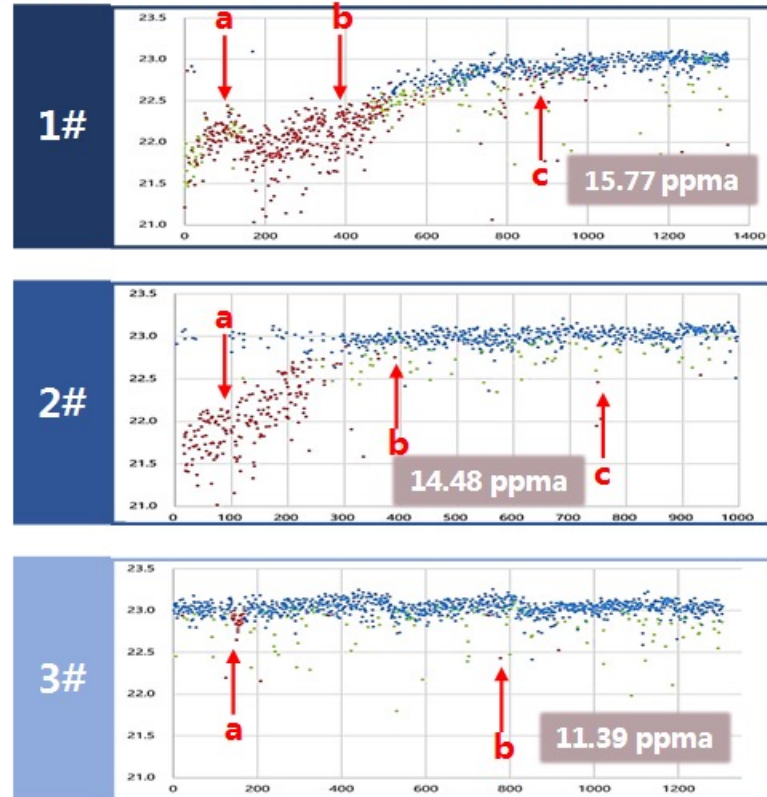


- **Supply chain:** Cost & reliability
- **Feasibility:** implementation at mass scale production
- **Continuous improvement** on-going materials/processes

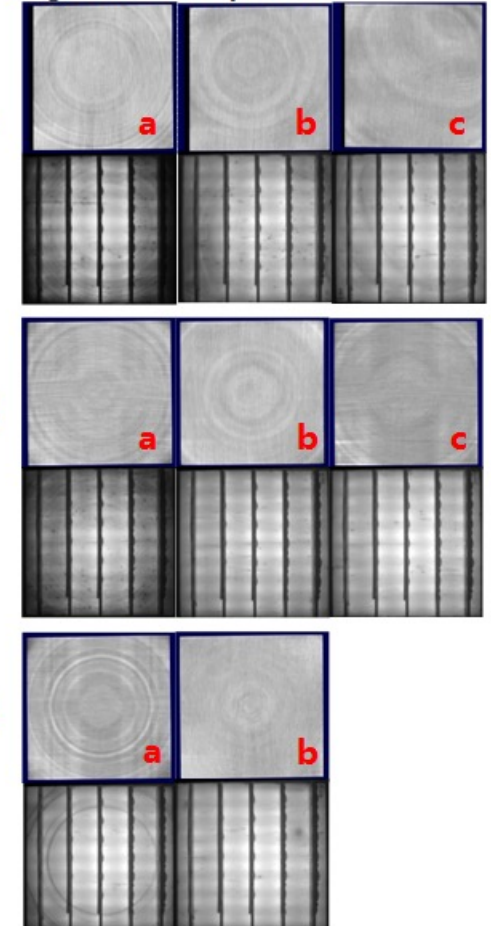
Industrial challenges: n-type wafer EL “ring” effect

- Ring effects under EL is a well-known phenomena for n-type, with no impact in power.
- Strong correlation with the oxygen concentration in wafers; oxygen precipitation.
- While low oxygen ingot growth technology developing, product performance study and new standards are widely discussed.

Verification of sequential wafers with black ring at the head of monocrystalline silicon rod with different initial oxygen content



PL of wafer and EL of cell with black rings at different positions



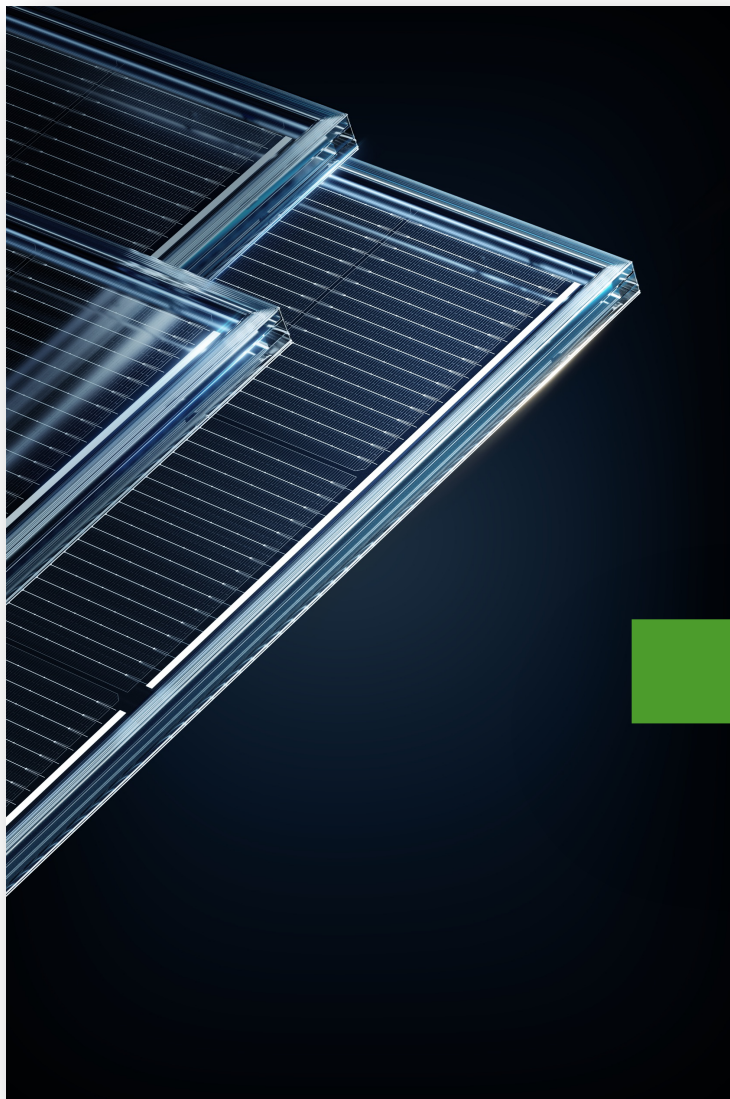
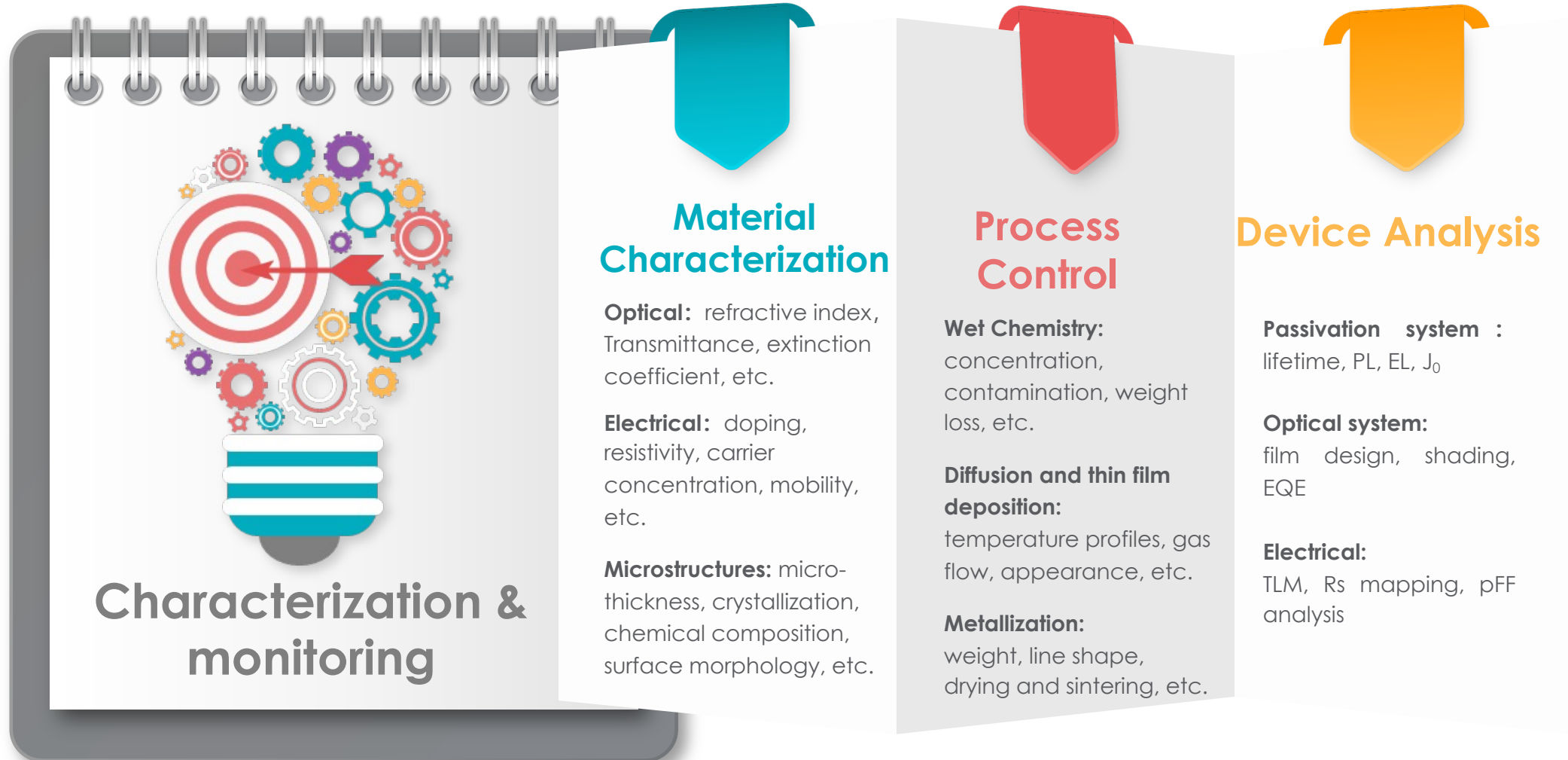


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- 04 Strategies for Success**
- 05 Conclusions

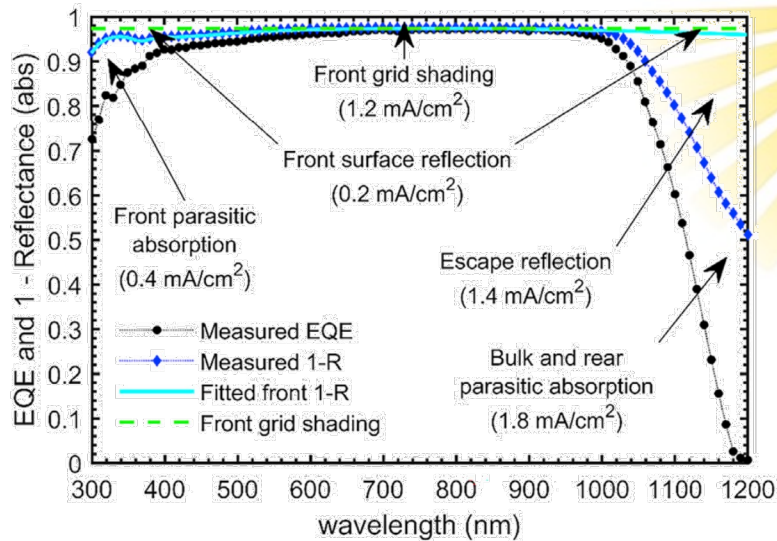
Strategies for Success: In-depth grasp of critical parameters

Well equipped R&D center enables comprehensive analysis & investigation

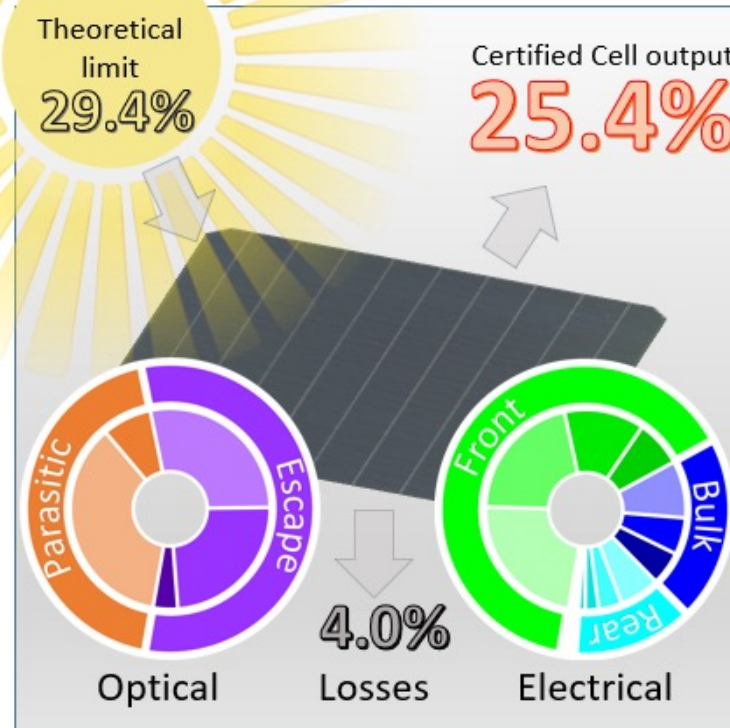


Strategies for Success: In-depth grasp of critical parameters

Optical Losses Analysis [3,4]

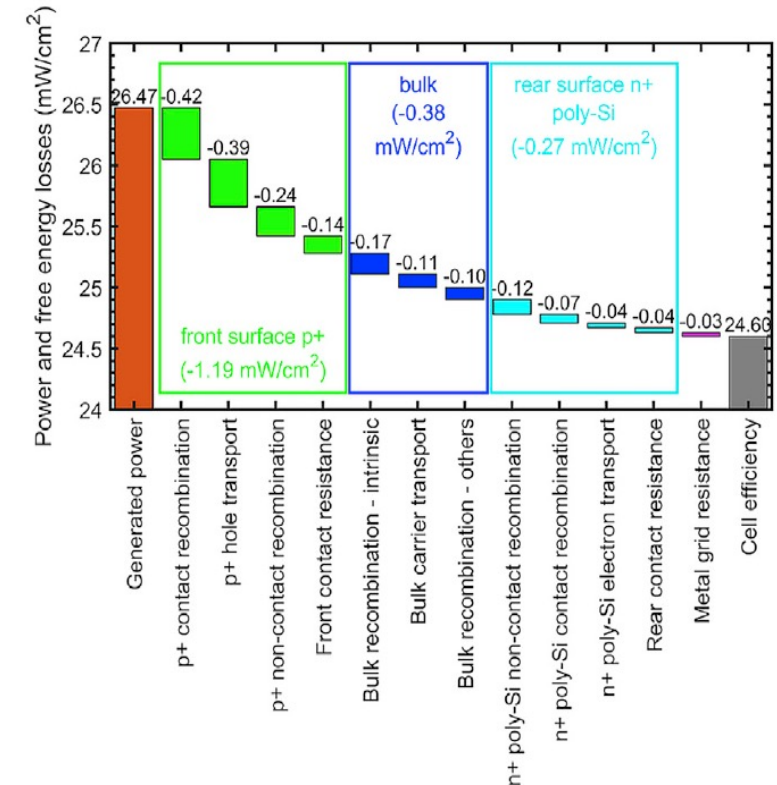


- **Significant optical losses:** bulk and rear parasitic absorption; escape reflection.
- **Potential solutions:** thinner films, optimized coating



November 2021 champion cell

Electrical Losses Analysis [3,4]



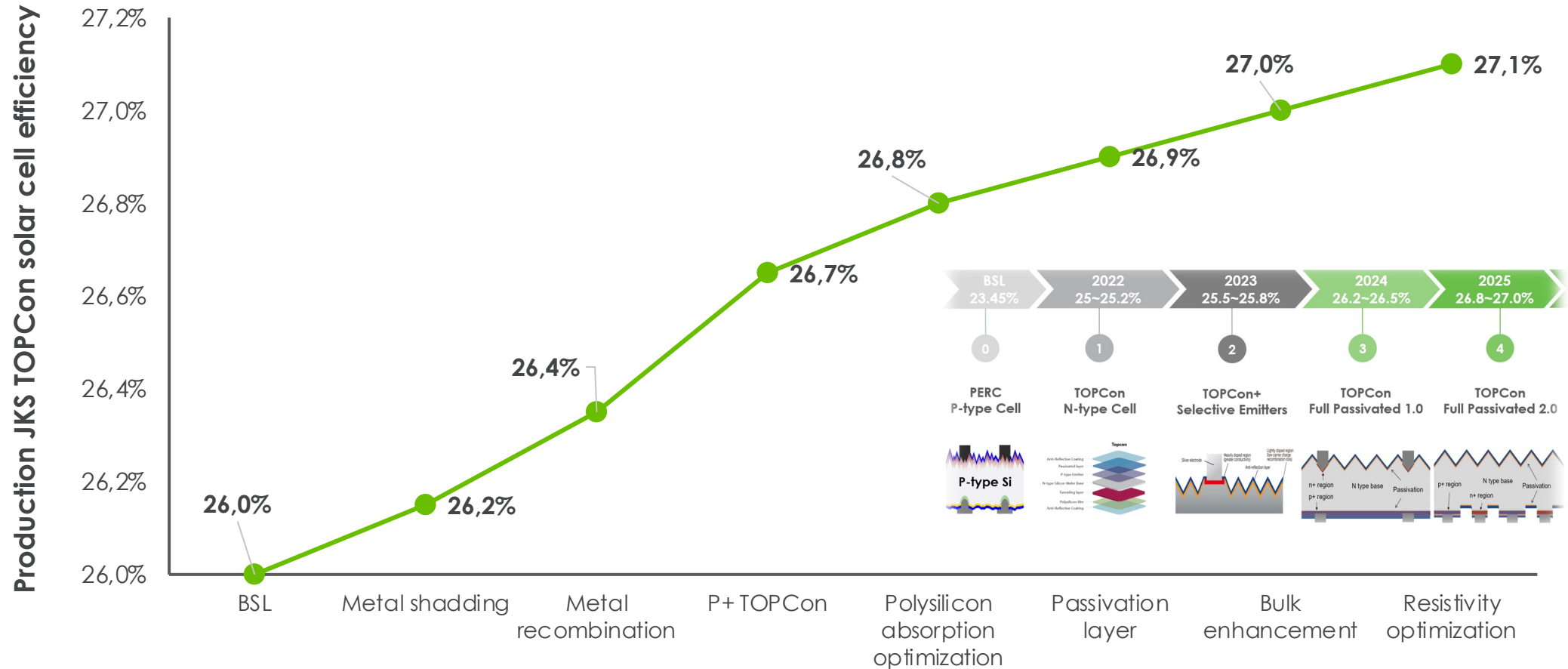
The **boron-diffused region on the front surface** accounted for losses of **1.19mW/cm²**, representing **63% of the total losses**

[3] Zheng P, Yang J, Wang Z, et al., "Detailed loss analysis of 24.8% large-area screen-printed n-type solar cell with polysilicon passivating contact," Cell Reports Physical Science 2, vol. 100603, October 20, 2021, doi: 10.1016/j.xcrp.2021.100603.

[4] Bonilla J, Giehl R, Magistris C and Murgioni R. TOPCon efficiency breakthrough from cell to PV modules. Photovoltaics International Ed. 48

Strategies for Success: Practical path

Steps towards >27% TOPCon solar cell in the near future

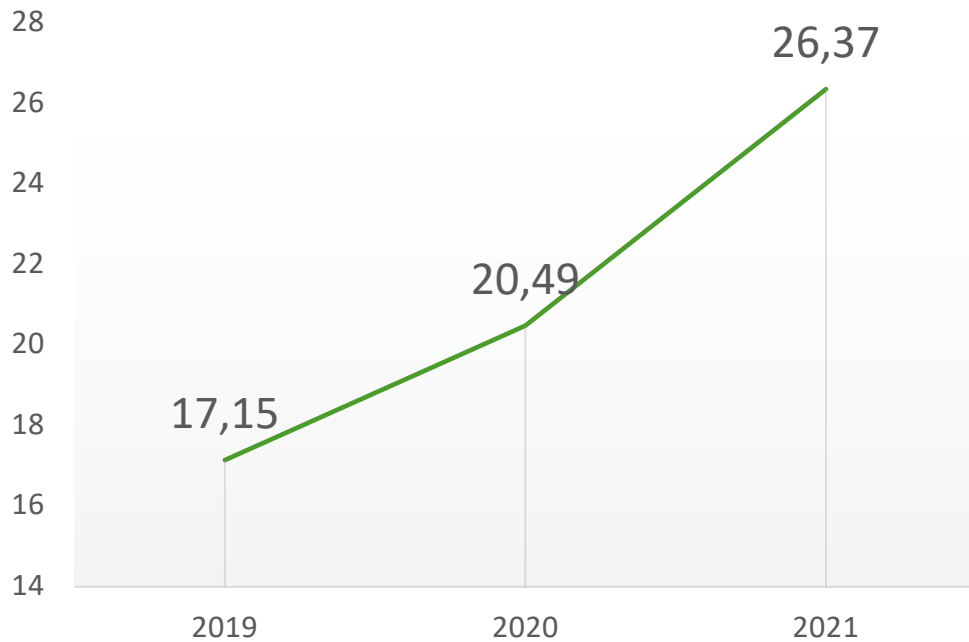


Strategies for Success: R&D Investment and Patent Forging

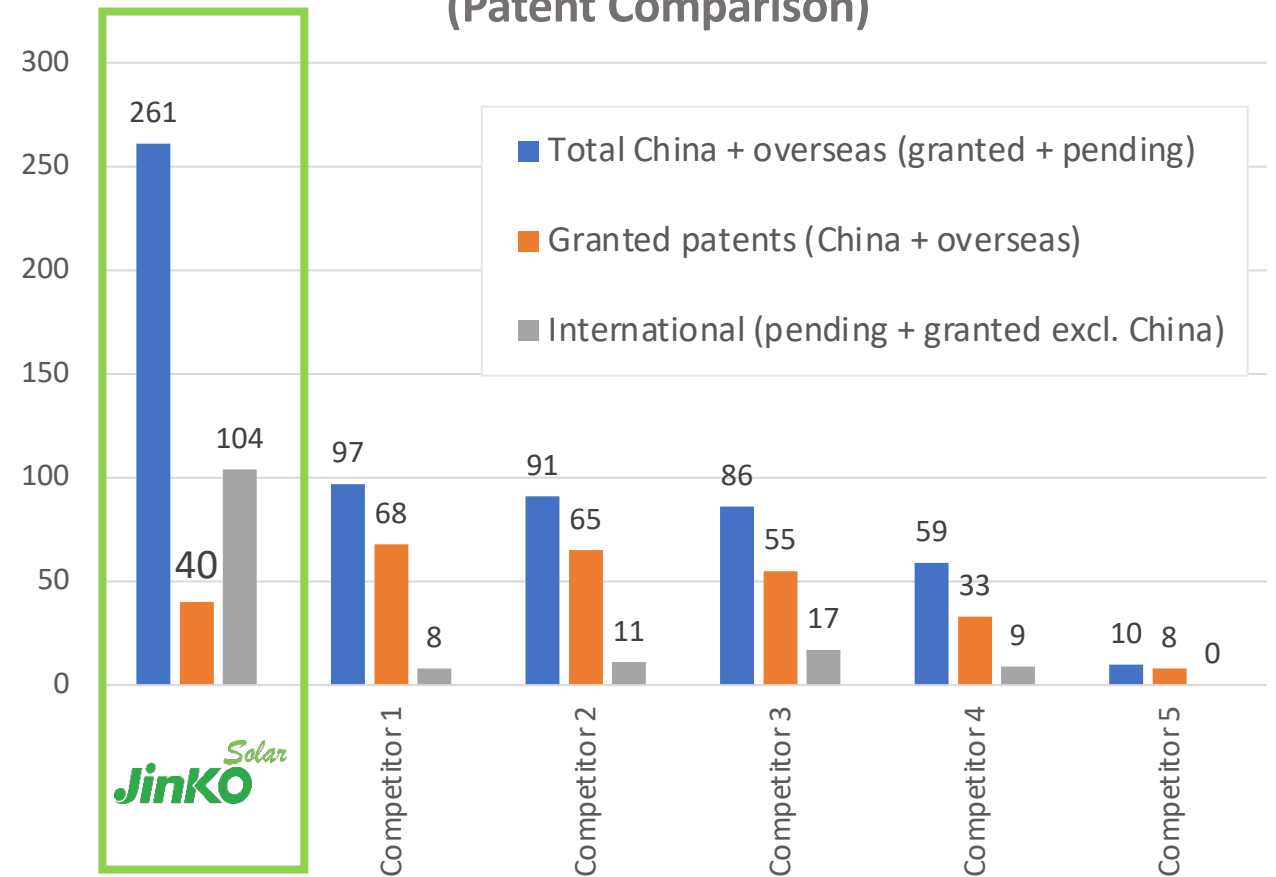


JinkoSolar's R&D Investment from 2019 to 2021

(Hundred Million RMB)



Intellectual Property TOPCon (Patent Comparison)

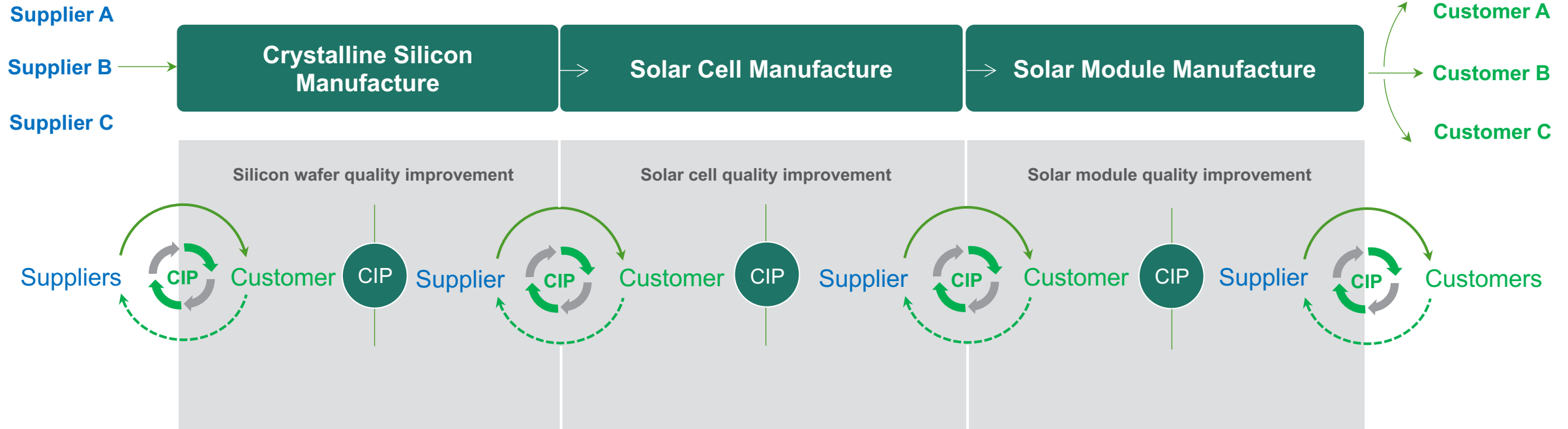
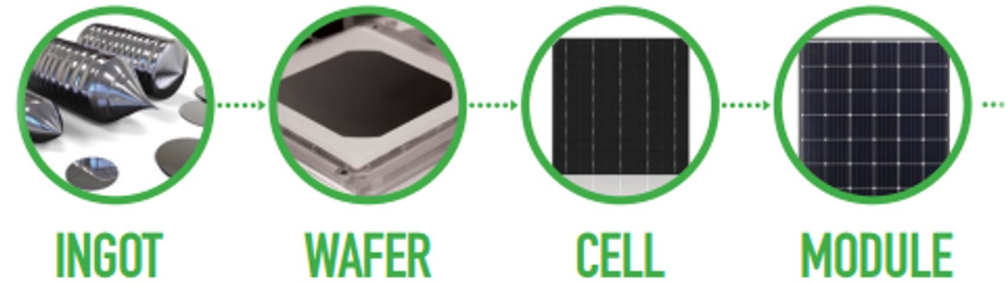


Source: before 2023/11 based on PatSnap public database..

Strategies for Success: Production Quality & Quality Assurance

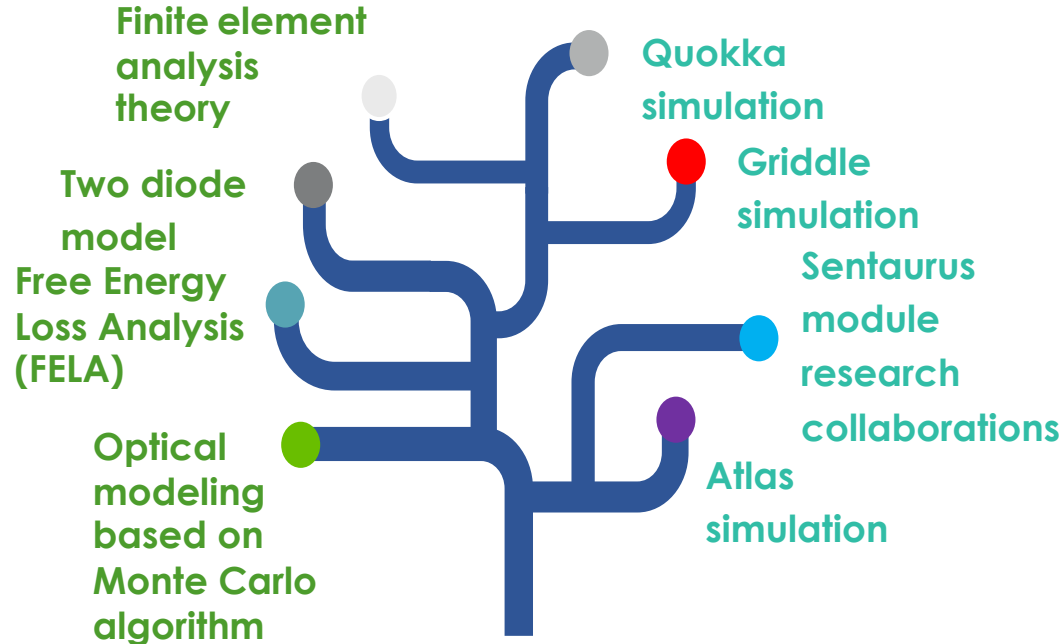


- Rigorous control over suppliers, production processes, and customer satisfaction
- Strong interaction between key departments (R&D, QA and Production)
- Pilot lines before mass production



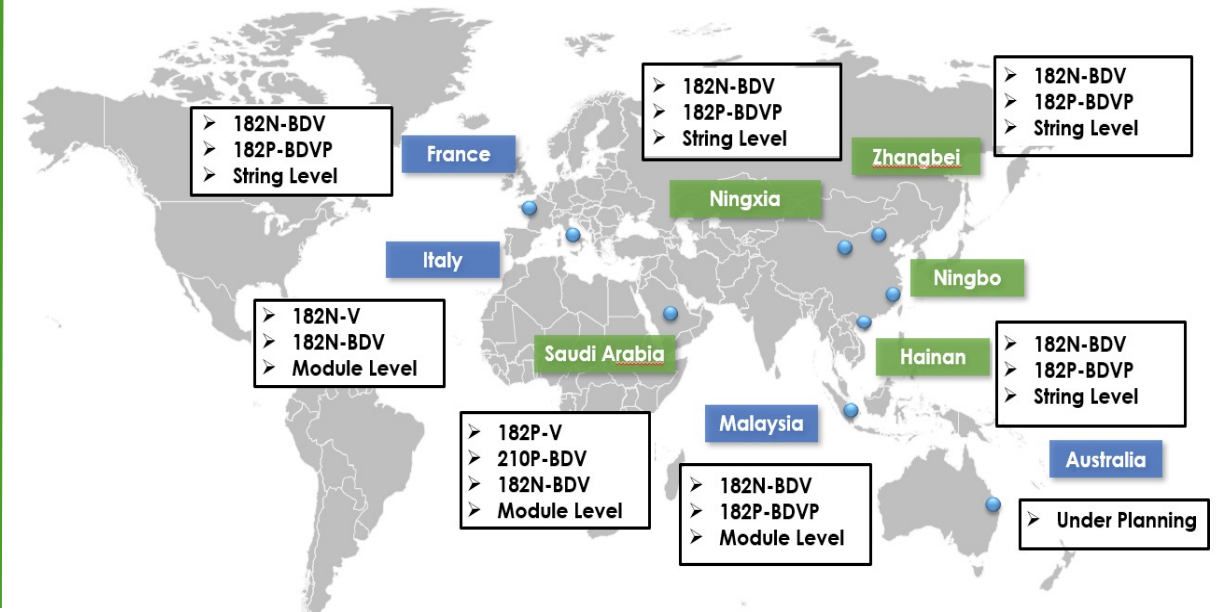
Strong R&D

fundamental research & simulation



Worldwide Field Tests

Energy yield & long-term performance



Strategies for Success: Testing & more testing



Historical Scorecard

The table below shows the history of top performance for all manufacturers featured in the 2023 Scorecard. Manufacturers are listed by the number of years they have been designated a Top Performer, in alphabetical order.



	2023	2022	2021	2020	2019	2018	2017	2016	2014
Jinko	•	•	•	•	•	•	•	•	•

Factory Witness, Characterizations and Light-Induced Degradation Measurement								
Thermal Cycling	Damp Heat	Backsheet Durability Sequence	Mechanical Stress Sequence	Hail Stress Sequence	Potential-Induced Degradation	LETID Sensitivity	PAN File & IAM Profile	Field Exposure
TC 200	DH 1000	DH 1000	Static Mechanical Load	Hail	85°C, 85%RH MSV (+ and/or -) 192 hrs	LETID 162 hrs (75°C, Isc-Imp)	PAN File	Field Exposure 6 Months
Characterization	Characterization	UV 65 kWh/m ²	Dynamic Mechanical Load	Characterization	Characterization	Characterization	IAM Profile	Characterization
TC 200	DH 1000	Characterization	Dynamic Mechanical Load	Dynamic Mechanical Load	Characterization	LETID 162 hrs (75°C, Isc-Imp)	Characterization	Characterization
Characterization	Characterization	TC 50 + HF 10	Characterization	Characterization	Characterization	Characterization	Characterization	Field Exposure 6 Months
TC 200	Stabilization 80°C, Isc, 48 hrs	UV 65 kWh/m ²	TC 50 + HF 10	TC 50 + HF 10	Characterization	LETID 162 hrs (75°C, Isc-Imp)	Characterization	Characterization
Characterization	Characterization	Characterization	Characterization	Characterization	Characterization	Characterization	Characterization	Characterization
		TC 50 + HF 10						
		UV 65 kWh/m ²						
		Characterization						
		TC 50 + HF 10						
		UV 6.5 kWh/m ²						
		Characterization						

<https://scorecard.pvel.com/top-performers/>

Three Times Reliability Test

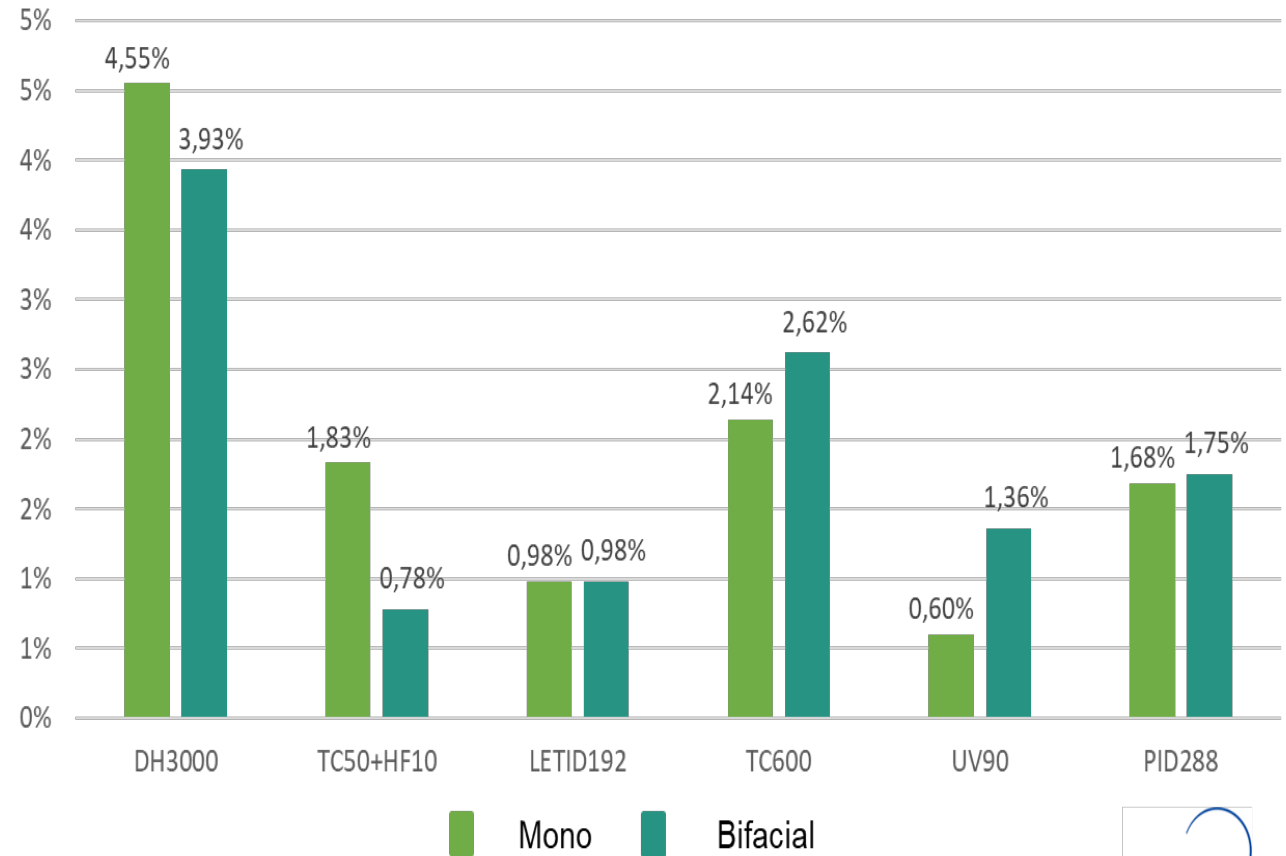
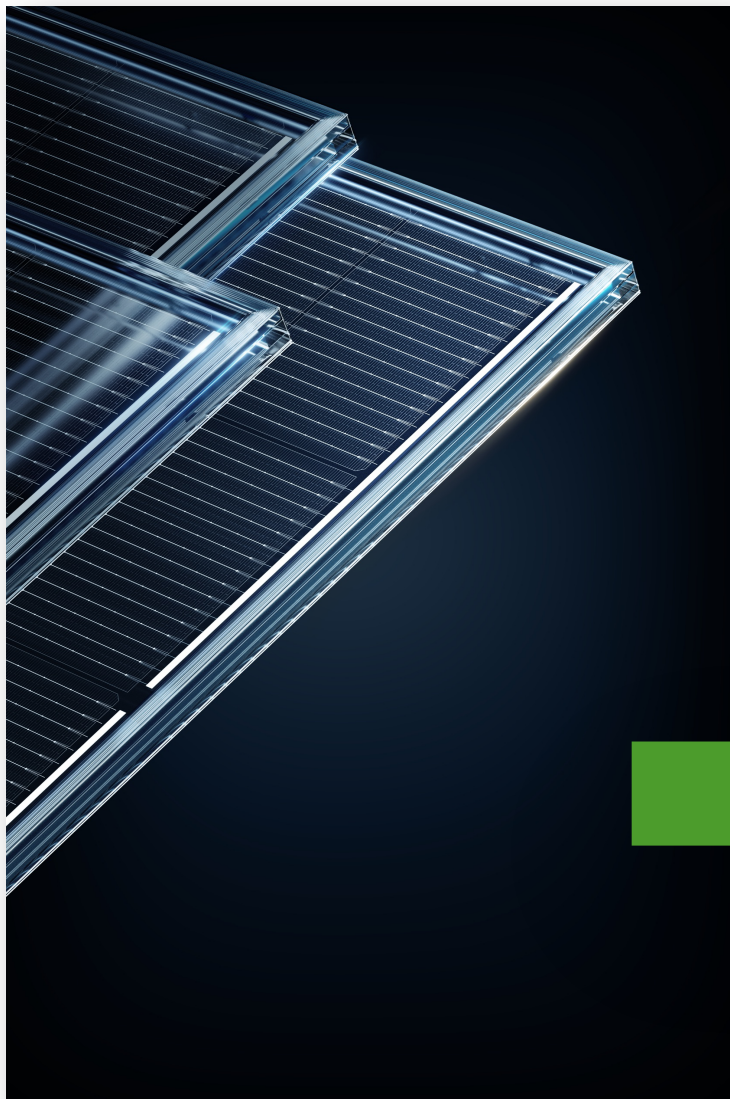


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Conclusions: JinkoSolar and TOPCon



➤ Foundation in R&D:

- **Robust** - cornerstone before product launches.
- **Proactive** measures are taken to address potential issues and ensure seamless integration.

➤ Continuous Learning Process:

- Mass production involves a learning process.
- **Correction** is acknowledged as part of the process, **but emphasis on proactive quality check & prevention.**

➤ Committed decisions:

- Decision driven by **data, test and long-term realistic goals**

➤ Readiness and Resilience:

- Challenges require **mitigation, innovation and dedications to quality.**

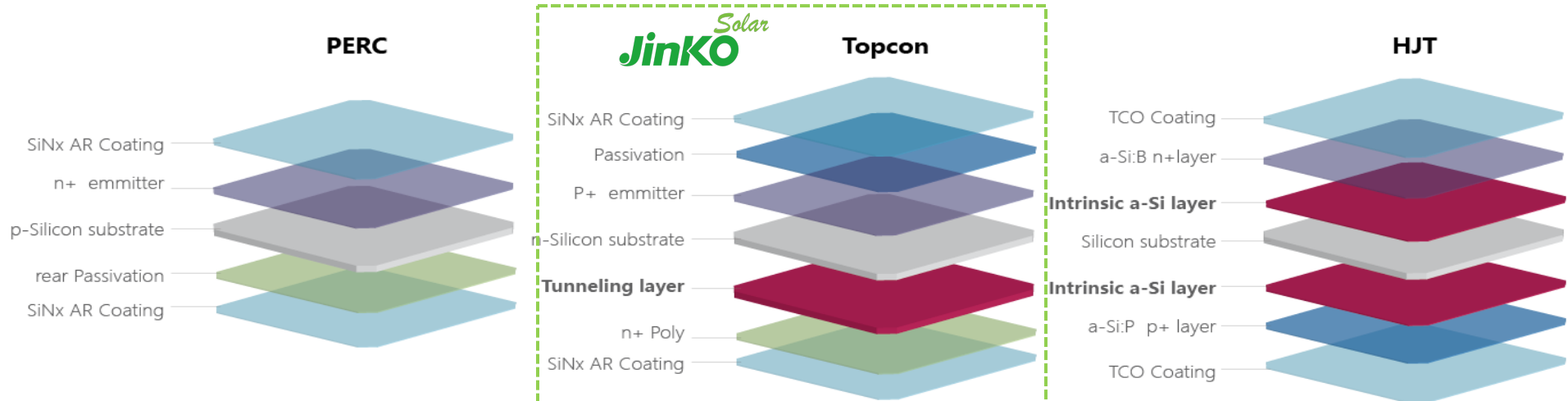


Thank you!

Johanna Bonilla

Technical Product Manager Europe

Technical Roadmap: Why TOPCon?



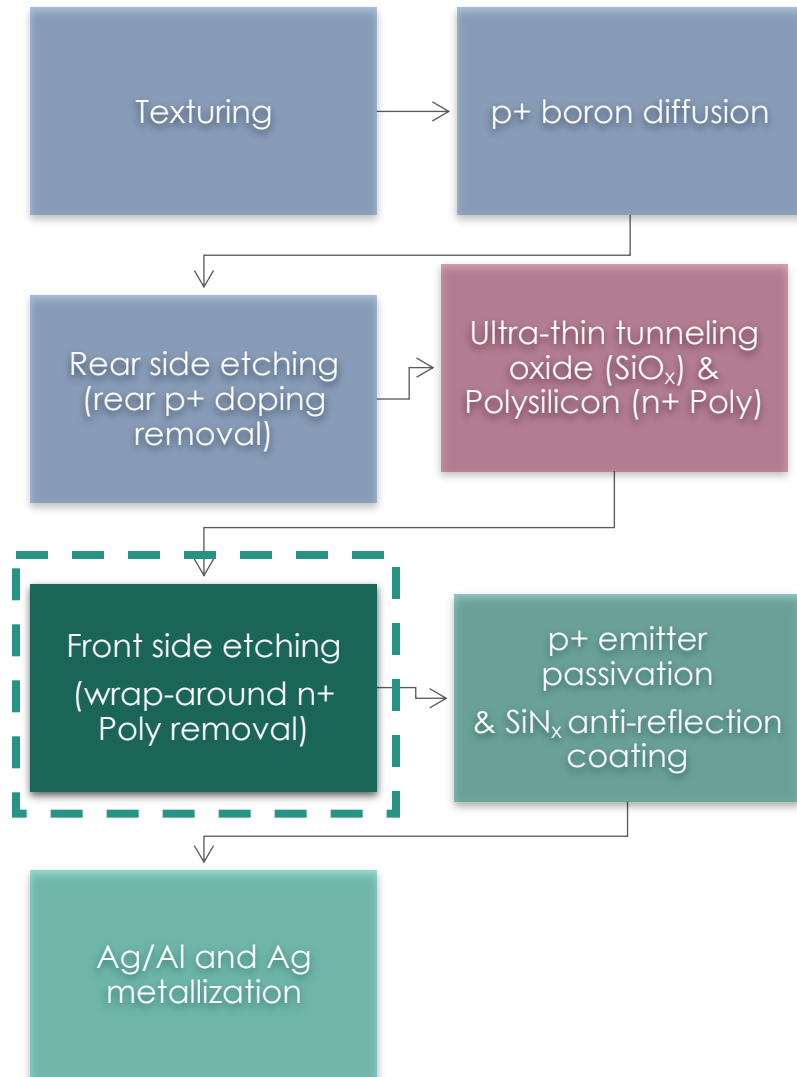
Theoretical Ultimate Efficiency ^[1,2]	24.5%	28.7%	28.5%
Temperature Coefficient	~-0.34	~-0.29	~-0.27
Bifaciality	~70	~80	~85
PID Risk	PID-p	PID-p	PID resistant
Delamination Risk	Low	Low	High
Moisture Sensitivity	**	***	*****
Hot Spot Risk	**	**	*****
Cost	BSL	~BSL	+~3cent/W

[1] Brendel, R., Rienaeker, M. & Peibst, R. 2016, "A quantitative measure for the carrier selectivity of contacts to solar cells", Proc. 32nd EU PVSEC, Munich, Germany, doi:10.4229/EUPVSEC201620162CO.4.1.

[2] Brendel, R. & Peibst, R. 2016, "Contact selectivity and efficiency in crystalline silicon photovoltaics", IEEE J. Photovolt., Vol. 6, No. 6, pp.1413–1420, doi:10.1109/JPHOTOV.2016.2598267.

Industrial challenges:

Cell process Wrap-around n+ poly removal



➤ **Removal:** Since polysilicon is inherently deposited on both sides of the wafer, a wrap-around etching using mass production feasible chemical wet-bench is performed. Using appropriate process control, the front side p+ emitter can be well protected

Before



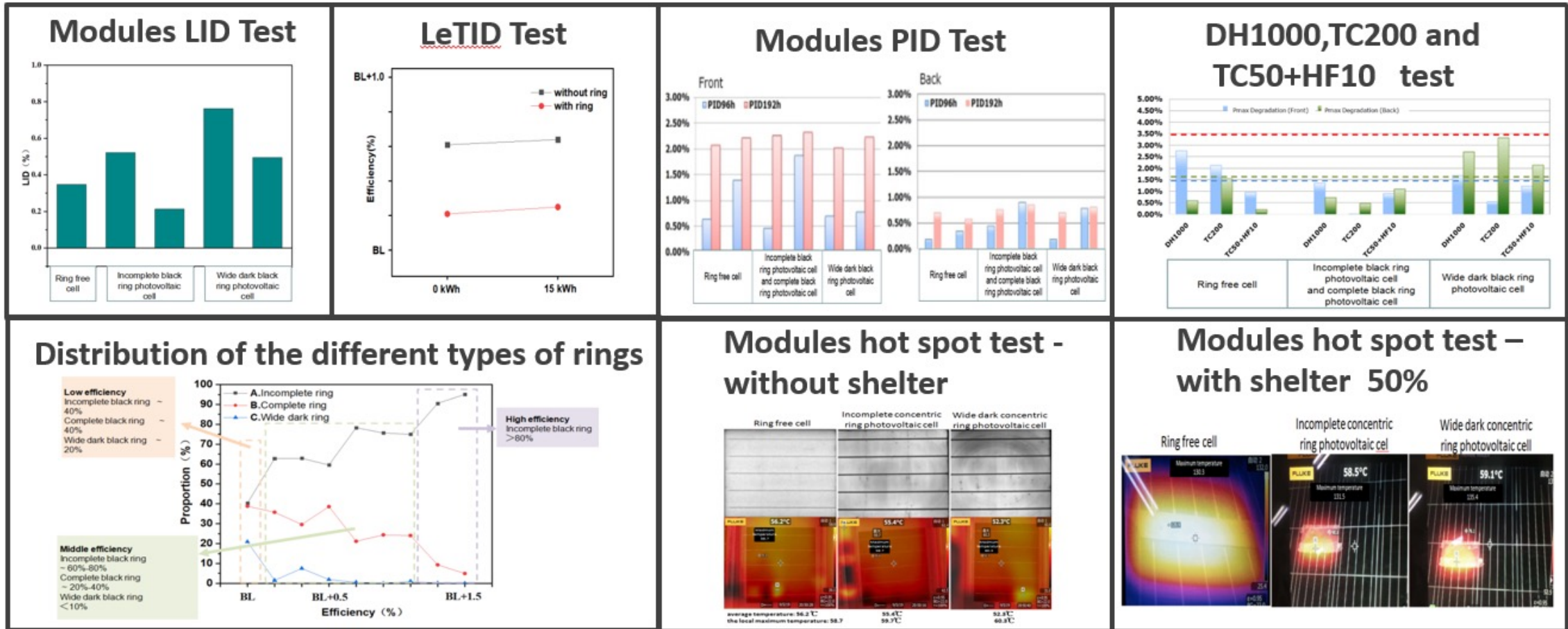
After



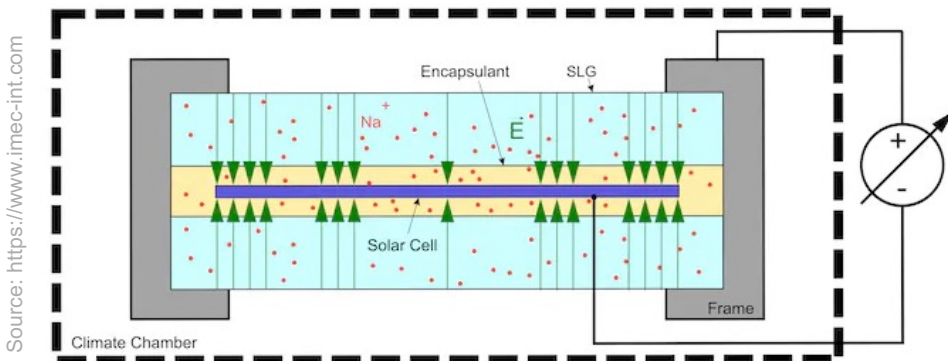
The front side borosilicate glass (BSG) and the rear side phosphosilicate glass (PSG) layers are removed in diluted HF solution

Industrial challenges: n-type wafer EL “ring” effect

Various performance comparison study between cells with and without ring effects demonstrate **no clear correlation between rings effects with degradation problems.**



Potential-Induced Degradation (PID)



Source: <https://www.imec-int.com>

PID: ion drift (mostly sodium, Na) towards the solar cell under influence of a strong electric field (green arrows).

PID 3rd party results for JKS Dual Glass Modules

Output Power Degradation after PID Test



Module type: JKM550N-72HL4-BDV

ΔPmpp [%]	After 96h	After 192h
Min	-0,61%	-0,91%
Max	-0,88%	-1,20%
Average	-0,78%	-1,09%



What?

- **PID-s (shunting):** Sodium ions diffusing into silicon stacking faults & shunting the cell
- **PID-p (polarization):** temporary & reversible degradation of the passivation layer, due to a surface recombination increase

Why?

- Expose to frequent high- voltage stress causing power drop

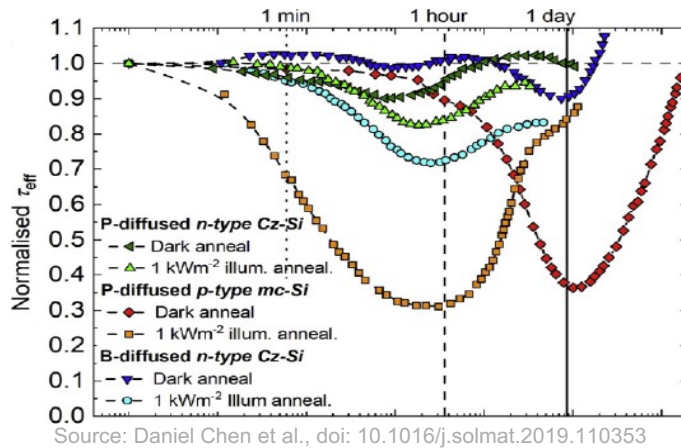
TOPCon

- PID-p sensitivity
- Bifacial cells in glass/glass are more sensitive
- Thinner layers also seem to be more sensitive

Tiger Neo Utility — Enhanced reliability

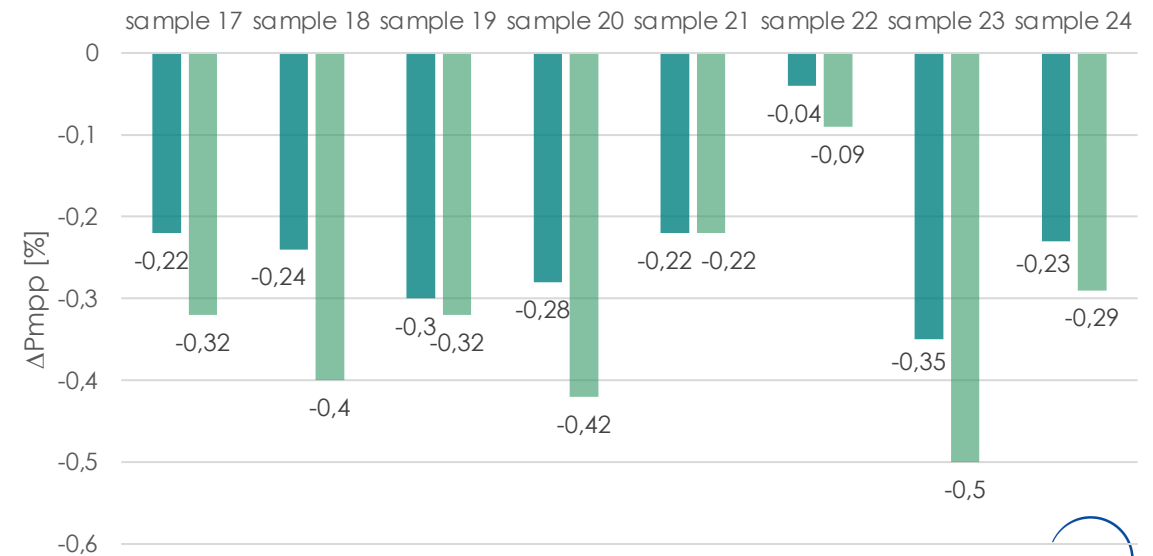
Light and elevated Temperature-Induced Degradation (LeTID)

LeTID Degradation Comparison & Recovery in boron and phosphorus diffused n-type Cz-Si and phosphorus diffused p-type mc-Si



LeTID 3rd party results for JKS Dual Glass Modules

Output Power Degradation after LeTID Test



Module type: JKM595N-78HL4-BDV

ΔPmpp [%]	After 300h
Min	-0,38%
Max	-0,45%
Average	-0,42%

What?

- **Phenomenon not a fundamental mechanism**- it could be observed & measured . It is a temperature driven condition as a result of hydrogenation

Why?

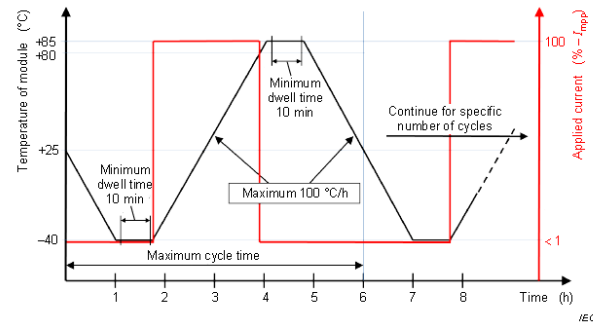
- **high irradiance at higher temperatures after hundreds of hours of light exposure**

TOPCon

- Presence but limited due to absence of BO LID
- Firing- induced degradation in the SiOx/n+Poly passivation
- Hydrogenation- critical for chemical passivation for SiOx/n+Poly

Tiger Neo Utility – Enhanced reliability

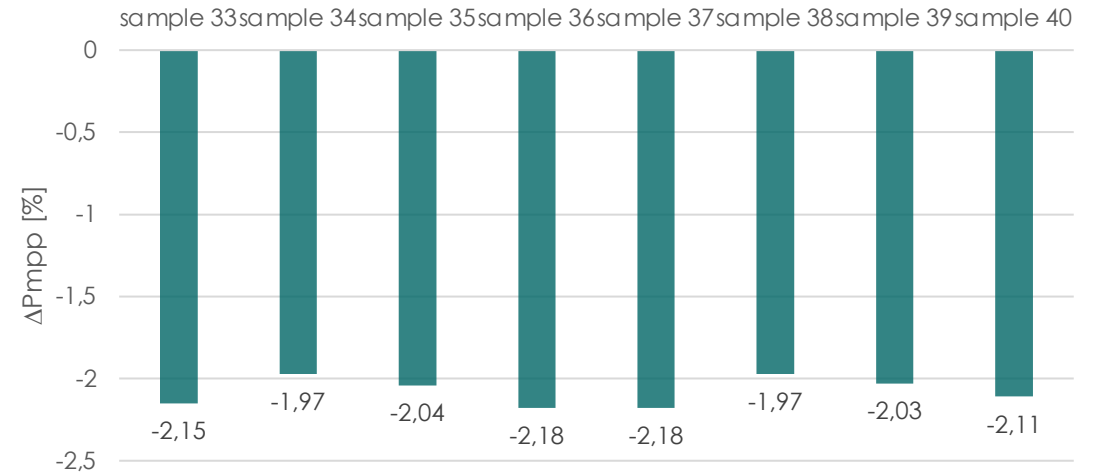
Thermal Cycling (TC)-400



Module type: JKM550N-72HL4-BDV

ΔP_{mpp} [%]	After 400 cycles
Min	-0,38%
Max	-0,45%
Average	-0,42%

Output Power Degradation after TC400 testing



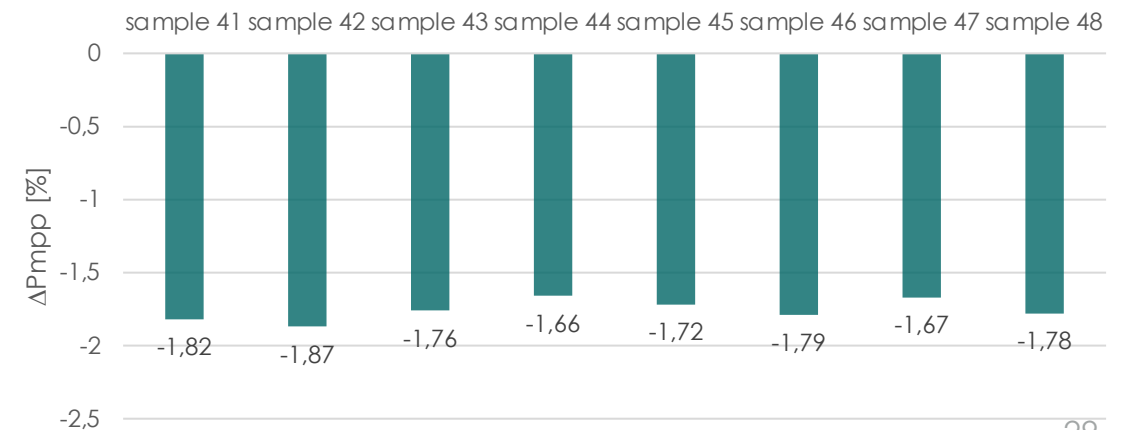
Damp Heat (DH)-2000



Module type: JKM550N-72HL4-BDV

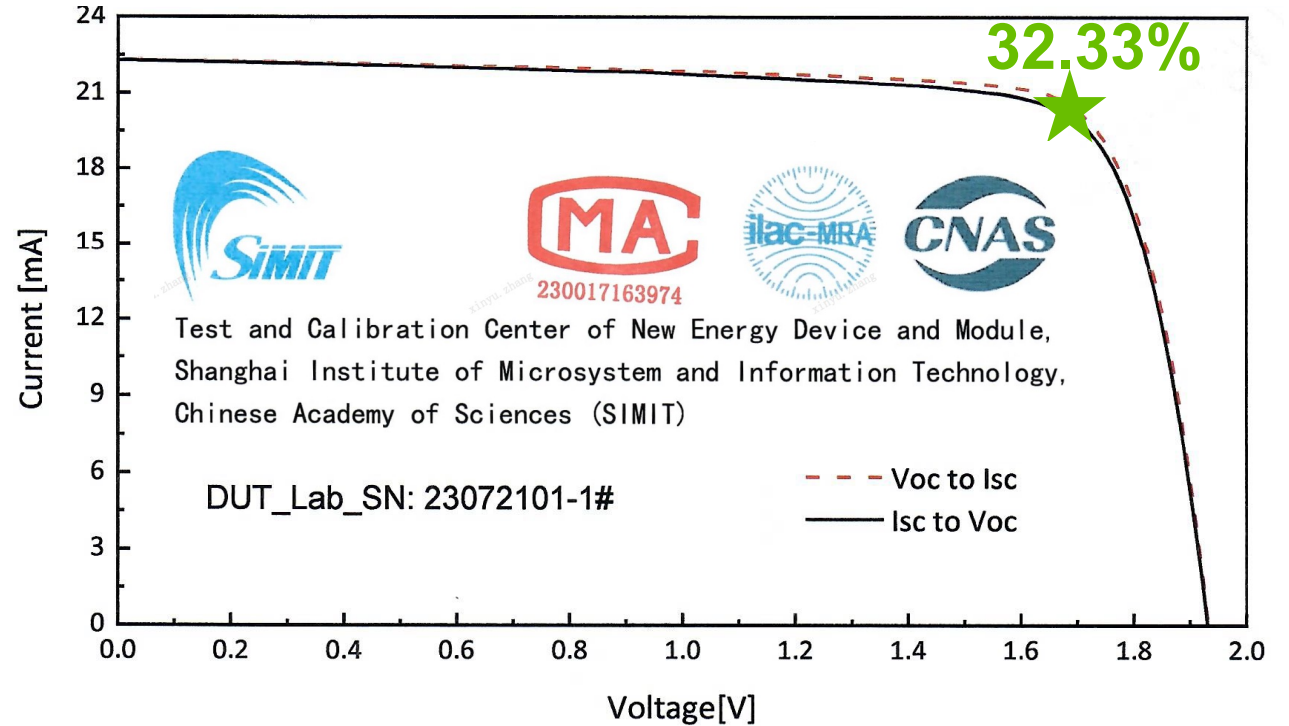
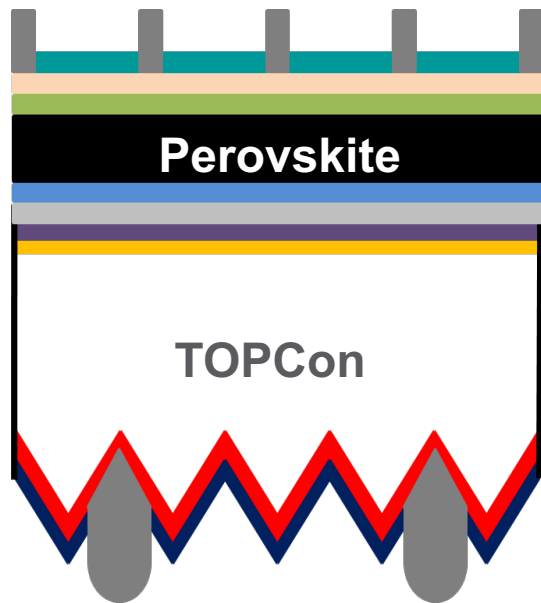
ΔP_{mpp} [%]	After 2000h
Min	-0,38%
Max	-0,45%
Average	-0,42%

Output Power Degradation after DH2000



Technical Roadmap: Development trend

JinkoSolar's **New Cell Efficiency Record of 32.33%** achieved on perovskite/TOPCon tandem



- ① **Surface passivation:** optimization of the passivation layer
- ② **Bulk passivation:** additive engineering to lower the hysteresis effect
- ③ **Recombination layer optimization:** high quality TCO with low resistance